


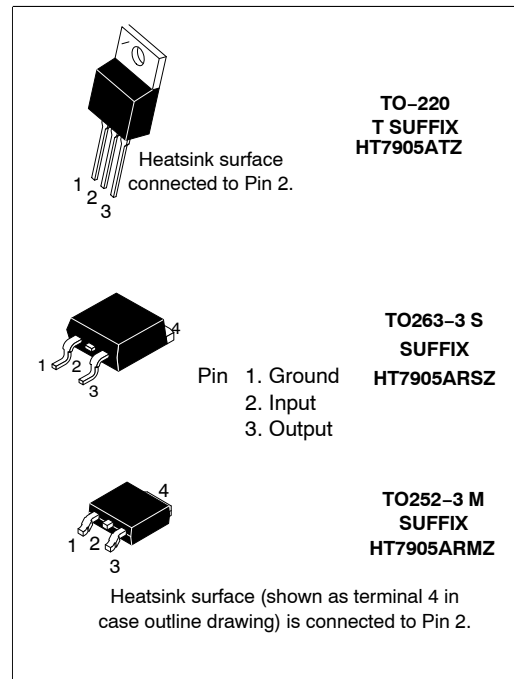
## Negative-Voltage Regulators

### DESCRIPTION

This series of fixed-negative voltage monolithic integrated circuit voltage regulators is designed to complement Series  $\mu$ A7800 in a wide range of applications. These applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. Each of these regulators can deliver up to 1.5A of output current. The internal limiting and thermal shutdown features of these regulators make them essentially immune to overload. In addition to use as fixed-voltage regulators, these devices can be used with external components to obtain adjustable output voltages and current and also as the power pass element in precision regulators.

- **3-Terminal Regulators**
- **Output Current Up to 1.5 A**
- **No External Components**
- **Internal Thermal Overload Protection**
- **High Power Dissipation Capability**
- **Internal Short-Circuit Current Limiting**
- **Output Transistor Safe-Area Compensation**

Nominal output voltage	Regulator	
-5V	7905A	
-6V	7906A	
-8V	7908A	
-9V	7909A	
-12V	7912A	
-15V	7915A	
-18V	7918A	
-24V	7924A	



### Absolute maximum ratings over operating temperature range (unless otherwise noted)

	79-- A	UNIT
Input voltage	7924A	-40
	All others	-35
Continuous total dissipation at 25 °C free-air temperature	2	W
Continuous total dissipation at (or below) 25 °C case temperature	15	
Operating free-air, case, or virtual junctions temperature range	0 to 150	
Storage temperature range	-65 to 150	°C
Lead temperature 3.2 mm (1/8 inch) from case for 10 seconds	260	

### Recommended operating conditions

PARAMETER	MIN	MAX	UNIT
Input voltage $V_I$	7905A	-7	V
	7906A	-8	
	7908A	-10.5	
	7912A	-14.5	
	7915A	-17.5	
	7918A	-21	
	7924A	-27	
Output current, $I_O$		1.5	A
Operating virtual junction temperature, $T_J$	0	125	°C

**7905A electrical characteristics at specified virtual junction temperature,  $V_I = -10V$ ,  $I_O = 500mA$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS*		7905A			UNIT
			MIN	TYP	MAX	
Output voltage**		25°C	-4.8	-5	-5.2	V
	$I_O = 5mA$ to 1A, $V_I = -7V$ to -20V, $P \leq 15W$	0°C to 125°C	-4.75	-5	-5.25	
Input regulation	$V_I = -7V$ to -25V	25°C		12.5	50	mV
	$V_I = -8V$ to -12V			4	15	
Ripple rejection	$V_I = -8V$ to -18V, $f = 120Hz$	0°C to 125°C	54	60		dB
Output regulation	$I_O = 5mA$ to 1.5A	25°C		15	100	mV
	$I_O = 250mA$ to 750mA			5	50	
Temperature coefficient of output voltage	$I_O = 5mA$	0°C to 125°C		-0.4		mV/°C
Output noise voltage	$f = 10$ Hz to 100 KHz	25°C		125		μV
Dropout voltage	$I_O = 1A$	25°C		1.6		V
Bias current		25°C		1.5	2	mA
Bias current change	$V_I = -7V$ to -25V	0°C to 125°C		0.15	0.5	
	$I_O = 5mA$ to 1A			0.08	0.5	
Peak output current		25°C		2.1		A

**7906A electrical characteristics at specified virtual junction temperature,  $V_I = -11V$ ,  $I_O = 500mA$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS*		7906A			UNIT
			MIN	TYP	MAX	
Output voltage**		25°C	-5.75	-6	-6.25	V
	$I_O = 5mA$ to 1A, $V_I = -8V$ to -21V, $P \leq 15W$	0°C to 125°C	-5.7	-6	-6.3	
Input regulation	$V_I = -8V$ to -25V	25°C		12.5	120	mV
	$V_I = -9V$ to -13V			4	60	
Ripple rejection	$V_I = -9V$ to -19V, $f = 120Hz$	0°C to 125°C	54	60		dB
Output regulation	$I_O = 5mA$ to 1.5A	25°C		15	120	mV
	$I_O = 250mA$ to 750mA			5	60	
Temperature coefficient of output voltage	$I_O = 5mA$	0°C to 125°C		-0.4		mV/°C
Output noise voltage	$f = 10$ Hz to 100 KHz	25°C		150		μV
Dropout voltage	$I_O = 1A$	25°C		1.6		V
Bias current		25°C		1.5	2	mA
Bias current change	$V_I = -8V$ to -25V	0°C to 125°C		0.15	1.3	
	$I_O = 5mA$ to 1A			0.08	0.5	
Peak output current		25°C		2.1		A

\* Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately.

\*\* This specification applies only for dc power dissipation permitted by absolute maximum ratings.

**7908A electrical characteristics at specified virtual junction temperature,  $V_I = -14V$ ,  $I_O = 500mA$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS*		7908A			UNIT
			MIN	TYP	MAX	
Output voltage**		25°C	-7.7	-8	-8.3	V
	$I_O = 5mA$ to 1A, $V_I = -10.5V$ to -23V, $P \leq 15W$	0°C to 125°C	-7.6	-8	-8.4	
Input regulation	$V_I = -10.5V$ to -25V	25°C		12.5	160	mV
	$V_I = -11V$ to -17V			4	80	
Ripple rejection	$V_I = -11.5V$ to -21.5V, $f = 120Hz$	0°C to 125°C	54	60		dB
Output regulation	$I_O = 5mA$ to 1.5A	25°C		15	160	mV
	$I_O = 250mA$ to 750mA			5	80	
Temperature coefficient of output voltage	$I_O = 5mA$	0°C to 125°C		-0.0		mV/°C
Output noise voltage	$f = 10Hz$ to 100 KHz	25°C		200		μV
Dropout voltage	$I_O = 1A$	25°C		1.6		V
Bias current		25°C		1.5	2	mA
Bias current change	$V_I = -10.5V$ to -25V	0°C to 125°C		0.15	1	
	$I_O = 5mA$ to 1A			0.08	0.5	
Peak output current		25°C		2.1		A

**7909A electrical characteristics at specified virtual junction temperature,  $V_I = -15V$ ,  $I_O = 500mA$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS*		7909A			UNIT
			MIN	TYP	MAX	
Output voltage**		25°C	-8.64	-9	-9.36	V
	$I_O = 5mA$ to 1A $V_I = -11.5V$ to -25V $P \leq 15W$	0 to 125 °C	-8.55	-9	-9.45	
Input regulation	$V_I = -11.5V$ to -25V	25°C		12.5	180	mV
	$V_I = -12V$ to -22.5V			4	90	
Ripple rejection	$V_I = -12.5V$ to -22.5V, $f = 120Hz$	25°C	54	60		dB
Output regulation	$I_O = 5mA$ to 1.5A	25°C		15	180	mV
	$I_O = 250mA$ to 750mA			5	90	
Temperature coefficient of output voltage	$I_O = 5mA$	0 to 125 °C		-0.8		mV/°C
Output noise voltage	$f = 10Hz - 100Hz$	25°C		225		μV
Dropout voltage	$I_O = 1A$	25°C		1.6		V
Bias current		25°C		1.5	2	mA
Bias current change	$V_I = -11.5V$ to -25V	0 to 125 °C		0.15	1	
	$I_O = 5mA$ to 1A			0.08	0.5	
Peak output current		25°C		2.1		A

\* Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately.

\*\* This specification applies only for dc power dissipation permitted by absolute maximum ratings.

**7912A electrical characteristics at specified virtual junction temperature,  $V_I = -19V$ ,  $I_O = 500mA$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS*		7912A			UNIT
			MIN	TYP	MAX	
Output voltage**		25°C	-11.5	-12	-12.5	V
	$I_O = 5mA$ to 1A, $V_I = -14.5V$ to -27V, $P \leq 15W$	0°C to 125°C	-11.4	-12	-12.6	
Input regulation	$V_I = -14.5V$ to -30V	25°C		5	80	mV
	$V_I = -16V$ to -22V			3	30	
Ripple rejection	$V_I = -15V$ to -25V, $f = 120Hz$	0°C to 125°C	54	60		dB
Output regulation	$I_O = 5mA$ to 1.5A	25°C		15	200	mV
	$I_O = 250mA$ to 750mA			5	75	
Temperature coefficient of output voltage	$I_O = 5mA$	0°C to 125°C		-0.8		mV/°C
Output noise voltage	$f = 10 Hz$ to 100 KHz	25°C		300		μV
Dropout voltage	$I_O = 1A$	25°C		1.6		V
Bias current		25°C		2	3	mA
Bias current change	$V_I = -14.5V$ to -30V	0°C to 125°C		0.04	0.5	
	$I_O = 5mA$ to 1A			0.06	0.5	
Peak output current		25°C		2.1		A

**7915A electrical characteristics at specified virtual junction temperature,  $V_I = -23V$ ,  $I_O = 500mA$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS*		7915A			UNIT
			MIN	TYP	MAX	
Output voltage**		25°C	-14.4	-15	-15.6	V
	$I_O = 5mA$ to 1A, $V_I = -17.5V$ to -30V, $P \leq 15W$	0°C to 125°C	-14.25	-15	-15.75	
Input regulation	$V_I = -17.5V$ to -30V	25°C		5	100	mV
	$V_I = -20V$ to -26V			3	50	
Ripple rejection	$V_I = -18.5V$ to -28.5V, $f = 120Hz$	0°C to 125°C	54	60		dB
Output regulation	$I_O = 5mA$ to 1.5A	25°C		15	200	mV
	$I_O = 250mA$ to 750mA			5	75	
Temperature coefficient of output voltage	$I_O = 5mA$	0°C to 125°C		-1		mV/°C
Output noise voltage	$f = 10 Hz$ to 100 KHz	25°C		375		μV
Dropout voltage	$I_O = 1A$	25°C		1.6		V
Bias current		25°C		2	3	mA
Bias current change	$V_I = -17.5V$ to -30V	0°C to 125°C		0.04	0.5	
	$I_O = 5mA$ to 1A			0.06	0.5	
Peak output current		25°C		2.1		A

\* Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately.

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**7918A electrical characteristics at specified virtual junction temperature,  $V_I = -27V$ ,  $I_O = 500mA$  (unless otherwise noted)**

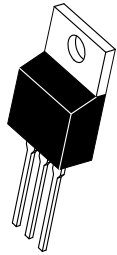
PARAMETER	TEST CONDITIONS*		7918A			UNIT
			MIN	TYP	MAX	
Output voltage**		25°C	-17.3	-18	-18.7	V
	$I_O = 5mA$ to 1A, $V_I = -21V$ to -33V, $P \leq 15W$	0°C to 125°C	-17.1	-18	-18.9	
Input regulation	$V_I = -21V$ to -33V	25°C		5	360	mV
	$V_I = -24V$ to -30V			3	180	
Ripple rejection	$V_I = -22V$ to -32V, $f = 120Hz$	0°C to 125°C	54	60		dB
Output regulation	$I_O = 5mA$ to 1.5A	25°C		30	360	mV
	$I_O = 250mA$ to 750mA			10	180	
Temperature coefficient of output voltage	$I_O = 5mA$	0°C to 125°C		-1.0		mV/°C
Output noise voltage	$f = 10Hz$ to 100 KHz	25°C		450		μV
Dropout voltage	$I_O = 1A$	25°C		1.6		V
Bias current		25°C		2	3	mA
Bias current change	$V_I = -21V$ to -33V	0°C to 125°C		0.04	1	
	$I_O = 5mA$ to 1A			0.06	0.5	
Peak output current		25°C		2.1		A

**7924A electrical characteristics at specified virtual junction temperature,  $V_I = -33V$ ,  $I_O = 500mA$  (unless otherwise noted)**

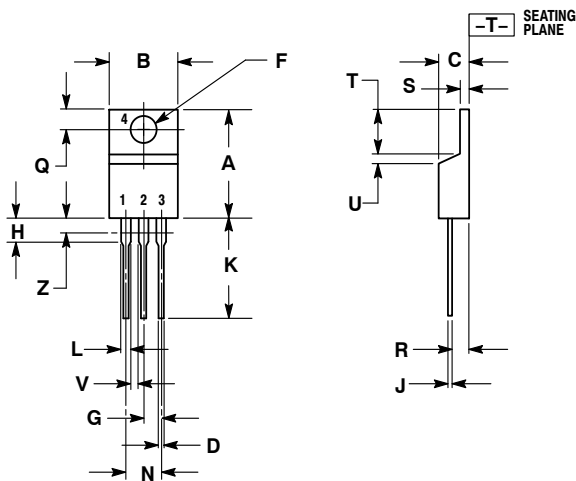
PARAMETER	TEST CONDITIONS*		7924A			UNIT
			MIN	TYP	MAX	
Output voltage**		25°C	-23	-24	-25	V
	$I_O = 5mA$ to 1A, $V_I = -27V$ to -38V, $P \leq 15W$	0°C to 125°C	-22.8	-24	-25.2	
Input regulation	$V_I = -27V$ to -38V	25°C		5	480	mV
	$V_I = -30V$ to -36V			3	240	
Ripple rejection	$V_I = -28V$ to -38V, $f = 120Hz$	0°C to 125°C	54	60		dB
Output regulation	$I_O = 5mA$ to 1.5A	25°C		85	480	mV
	$I_O = 250mA$ to 750mA			25	240	
Temperature coefficient of output voltage	$I_O = 5mA$	0°C to 125°C		-1		mV/°C
Output noise voltage	$f = 10Hz$ to 100 KHz	25°C		600		μV
Dropout voltage	$I_O = 1A$	25°C		1.6		V
Bias current		25°C		2	3	mA
Bias current change	$V_I = -27V$ to -38V	0°C to 125°C		0.04	1	
	$I_O = 5mA$ to 1A			0.06	0.5	
Peak output current		25°C		2.1		A

\* Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately.

\*\* This specification applies only for dc power dissipation permitted by absolute maximum ratings.



SCALE 1:1



TO-220, SINGLE GAUGE  
CASE 221AB-01  
ISSUE A

DATE 16 NOV 2010

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCHES.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.
4. PRODUCT SHIPPED PRIOR TO 2008 HAD DIMENSIONS S = 0.045 - 0.055 INCHES (1.143 - 1.397 MM)

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
H	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.020	0.024	0.508	0.61
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

STYLE 1:

- PIN 1. BASE
- 2. COLLECTOR
- 3. EMITTER
- 4. COLLECTOR

STYLE 2:

- PIN 1. BASE
- 2. EMITTER
- 3. COLLECTOR
- 4. EMITTER

STYLE 3:

- PIN 1. CATHODE
- 2. ANODE
- 3. GATE
- 4. ANODE

STYLE 4:

- PIN 1. MAIN TERMINAL 1
- 2. MAIN TERMINAL 2
- 3. GATE
- 4. MAIN TERMINAL 2

STYLE 5:

- PIN 1. GATE
- 2. DRAIN
- 3. SOURCE
- 4. DRAIN

STYLE 6:

- PIN 1. ANODE
- 2. CATHODE
- 3. ANODE
- 4. CATHODE

STYLE 7:

- PIN 1. CATHODE
- 2. ANODE
- 3. CATHODE
- 4. ANODE

STYLE 8:

- PIN 1. CATHODE
- 2. ANODE
- 3. EXTERNAL TRIP/DELAY
- 4. ANODE

STYLE 9:

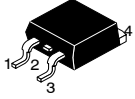
- PIN 1. GATE
- 2. COLLECTOR
- 3. EMITTER
- 4. COLLECTOR

STYLE 10:

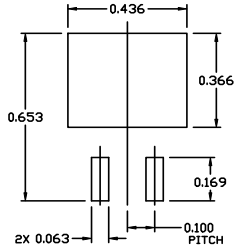
- PIN 1. GATE
- 2. SOURCE
- 3. DRAIN
- 4. SOURCE

STYLE 11:

- PIN 1. DRAIN
- 2. SOURCE
- 3. GATE
- 4. SOURCE

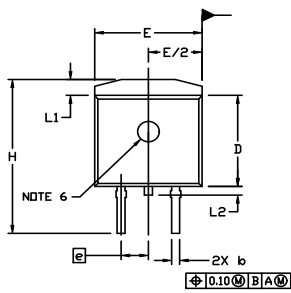


(TO-263, 3-LEAD) CASE  
 418AJ  
 ISSUE E



RECOMMENDED  
 MOUNTING FOOTPRINT

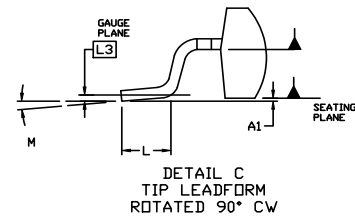
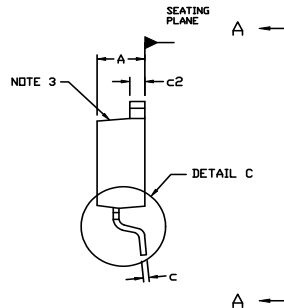
For additional information on our Pb-free strategy and soldering details, please download the DR Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERM/D.



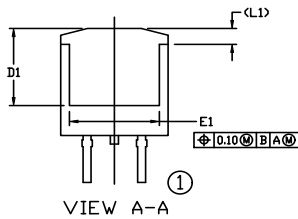
NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
2. CONTROLLING DIMENSION: INCHES
3. CHAMFER OPTIONAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.005 PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY AT DATUM H.
5. THERMAL PAD CONTOUR IS OPTIONAL WITHIN DIMENSIONS E, L1, D1, AND E1.
6. OPTIONAL MOLD FEATURE.
7. Ⓚ, Ⓛ ... OPTIONAL CONSTRUCTION FEATURE CALL OUTS.

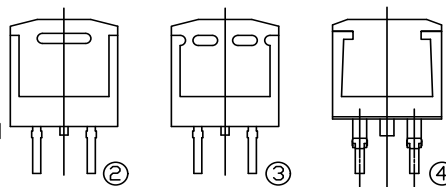
DIM	INCHES		MILLIMETERS	
	MIN.	MAX.	MIN.	MAX.
A	0.160	0.190	4.06	4.83
A1	0.000	0.010	0.00	0.25
b	0.020	0.039	0.51	0.99
c	0.012	0.029	0.30	0.74
c2	0.045	0.065	1.14	1.65
D	0.330	0.380	8.38	9.65
D1	0.260	---	6.60	---
E	0.380	0.420	9.65	10.67
E1	0.245	---	6.22	---
e	0.100	BSC	2.54	BSC
H	0.575	0.625	14.60	15.88
L	0.070	0.110	1.78	2.79
L1	---	0.066	---	1.68
L2	---	0.070	---	1.78
L3	0.010	BSC	0.25	BSC
M	-8°	8°	-8°	8°



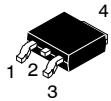
DETAIL C  
 TIP LEADFORM  
 ROTATED 90° CW



VIEW A-A



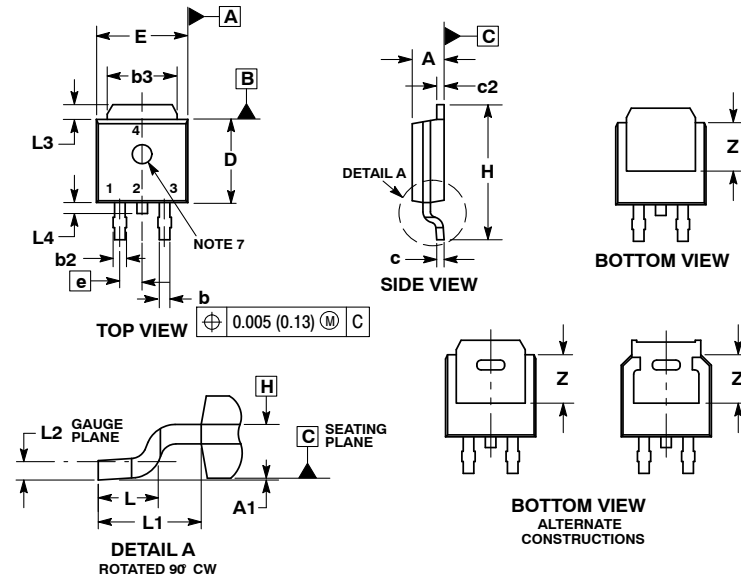
VIEW A-A  
 OPTIONAL CONSTRUCTIONS



SCALE 1:1

**TO252 (SINGLE GAUGE) CASE 369C**  
ISSUE F

DATE 21 JUL 2015



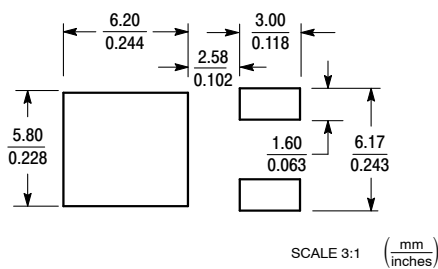
NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS b3, L3 and Z.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.008 INCHES PER SIDE.
5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.
7. OPTIONAL MOLD FEATURE.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.028	0.045	0.72	1.14
b3	0.180	0.215	4.57	5.46
c	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
E	0.250	0.265	6.35	6.73
e	0.090	BSC	2.29	BSC
H	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.114	REF	2.90	REF
L2	0.020	BSC	0.51	BSC
L3	0.035	0.050	0.89	1.27
L4	---	0.040	---	1.01
Z	0.155	---	3.93	---

- |  |  |   |   |  |
|--|--|---|---|--|
| <p>STYLE 1:<br/>PIN 1. BASE<br/>2. COLLECTOR<br/>3. EMITTER<br/>4. COLLECTOR</p> | <p>STYLE 2:<br/>PIN 1. GATE<br/>2. DRAIN<br/>3. SOURCE<br/>4. DRAIN</p>          | <p>STYLE 3:<br/>PIN 1. ANODE<br/>2. CATHODE<br/>3. ANODE<br/>4. CATHODE</p> | <p>STYLE 4:<br/>PIN 1. CATHODE<br/>2. ANODE<br/>3. GATE<br/>4. ANODE</p>              | <p>STYLE 5:<br/>PIN 1. GATE<br/>2. ANODE<br/>3. CATHODE<br/>4. ANODE</p>     |
| <p>STYLE 6:<br/>PIN 1. MT1<br/>2. MT2<br/>3. GATE<br/>4. MT2</p>                 | <p>STYLE 7:<br/>PIN 1. GATE<br/>2. COLLECTOR<br/>3. EMITTER<br/>4. COLLECTOR</p> | <p>STYLE 8:<br/>PIN 1. N/C<br/>2. CATHODE<br/>3. ANODE<br/>4. CATHODE</p>   | <p>STYLE 9:<br/>PIN 1. ANODE<br/>2. CATHODE<br/>3. RESISTOR ADJUST<br/>4. CATHODE</p> | <p>STYLE 10:<br/>PIN 1. CATHODE<br/>2. ANODE<br/>3. CATHODE<br/>4. ANODE</p> |

**SOLDERING FOOTPRINT\***



SCALE 3:1 (mm/inches)

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.